## Supplementary Materials

## 1. Determination of the Angle of Incidence and Thin Layer Cavity

## Thickness

In this section, $R(e)$ denotes the single beam reflectivity from the three phase system, $\mathrm{Pt}\left|\mathrm{H}_{2} \mathrm{O}\right| \mathrm{ZnSe}, R(a)$ is the single beam reflectivity from the air $\mid \mathrm{ZnSe}$ interface and $R(s)$ single beam reflectivity from the $\mathrm{H}_{2} \mathrm{O} \mid \mathrm{ZnSe}$ interface. The procedure used to determine the angle of incidence and the thin layer cavity thickness has been described in ref 32 and 38 of this paper. In short, the method first involves the measurement of the reflectivity for the empty IR cell, $R(a)$. Next the cell is filled with sulfate solution and the Pt electrode is inserted and pressed up against the IR window to form the thin layer configuration. The reflectivity for the electrode|solution|window interface, $R(e)$, is measured. The ratio $R(e) / R(a)$ is calculated from the experimental data and Fresnel equations in the matrix form are used to calculate $R(e) / R(a)$ from the optical constants of the electrode, solution and the window. The initial value of the angle of incidence is determined from the geometry of the optical set-up. However, the angle of incidence and thin layer cavity thickness are two adjustable parameters in the Fresnel matrix,


Fig. 1 Single beam reflectivities from: $R(e)-\mathrm{Pt}\left|\mathrm{H}_{2} \mathrm{O}\right| \mathrm{ZnSe} ; R(a)-\operatorname{air} \mid \mathrm{ZnSe}$ and $R(s)$ $-\mathrm{H}_{2} \mathrm{O} \mid \mathrm{ZnSe}$ interface when the system was optimized to angle incidence $\sim 31^{\circ}$.
which are used to fit the experimental data to produce a calculated curve of best fit. Therefore the final value of the angle of incidence may be different than the initial
estimate based on the geometry of the optical set-up.

In the present study, the optical set-up was aligned to carry out experiments at an angle of incidence $\sim 31^{\circ}$, which according to recent calculations (ref. 45 in this paper), is close to the global maximum of the mean squared electric field strength (MSEFS) for IR adsorption of sulfate. However, this particular angle of incidence is also close to the critical angle of the $\mathrm{ZnSe} \mid \mathrm{H}_{2} \mathrm{O}$ interface. Fig. 1 illustrates that a significant reflection of IR radiation occurs at the window|solution interface.

The single beam reflectivities of the three interfaces acquired from the experimental configuration optimized at an incidence angle of $\sim 31^{\circ}$ are plotted in Fig. 1. The data clearly shows that the values of $R(e)$ and $R(s)$ for the wavenumber range of approximately $1800-1600 \mathrm{~cm}^{-1}$ and those larger than $3100 \mathrm{~cm}^{-1}$ are identical. In these two regions, the reflectivity that is measured for the $\mathrm{Pt}\left|\mathrm{H}_{2} \mathrm{O}\right| \mathrm{ZnSe}$ system is essentially determined by the reflectivity at the $\mathrm{H}_{2} \mathrm{O} \mid \mathrm{ZnSe}$ interface making the signal from the three-phase system negligible. Note: the reflectivity from the $\mathrm{Pt}\left|\mathrm{H}_{2} \mathrm{O}\right| \mathrm{ZnSe}$ system cannot be less than the reflectivity from the $\mathrm{H}_{2} \mathrm{O} \mid \mathrm{ZnSe}$ interface.

The implication of this phenomenon is significant in the calculation of the angle of incidence and thin cavity thickness. Fig. 2 shows a typical "good" fit to the $R(e) / R(a)$ data. The fit was performed in the range $\sim 3500-1400 \mathrm{~cm}^{-1}$. However, as shown from the single reflectivities in Fig. 1, the two deep minima in the experimental $R(e) / R(a)$ curve of Fig. 2 are misleading since the reflectivity in these regions occur at the $\mathrm{H}_{2} \mathrm{O} \mid \mathrm{ZnSe}$ interface and not from the desired $\mathrm{Pt}\left|\mathrm{H}_{2} \mathrm{O}\right| \mathrm{ZnSe}$ system.


Fig. 2 Experimental (dashed line) and fitted IR reflectivity (dotted line) of the $\mathrm{Pt}(111)$ electrode in $0.1 \mathrm{M} \mathrm{Na}_{2} \mathrm{SO}_{4}+0.001 \mathrm{M} \mathrm{H}_{2} \mathrm{SO}_{4}$ solution for p-polarized light. The fitted incident angle and water gap thickness are $28.5^{\circ}$ and $5.0 \mu \mathrm{~m}$

The fits for this data provide incorrect values for the thin layer thickness and unusually low angles of incidence of approximately $28^{\circ}$. As a result, the MSEFS that is calculated using these values did not allow for correct subtraction of the IR contribution from the solution species in the p-polarized SNIFTIR spectra since the s-polarized IR spectra must be multiplied by the ratio of the MSEFS for p - and s-polarized radiation as shown in the following equation: $\left(\frac{\Delta R}{R}\right)_{s} \times \frac{\left\langle E_{p, a v e, 0 \rightarrow g a p}\right\rangle^{2}}{\left\langle E_{s, \text { ave }, 0 \rightarrow g a p}\right\rangle^{2}}$. This point is illustrated in Fig. 3, which shows that the resulting s-polarized spectrum after correcting for the calculated field strength (shown in black) has a positive band at $\sim 1100 \mathrm{~cm}^{-1}$. The intensity of this band is approximately $1 / 2$ of that observed in the spectrum acquired using p-polarized light (shown in red). After subtraction of the corrected spectrum for s-polarization from the spectrum for p-polarization the features due to the solution species are not removed (shown in blue).

However, despite this complication, the single reflectivities in Figure 1 can still be used to calculate $R(s) / R(a)$ and these curves could be used to calculate correct thin


Fig. 3 Calculated IR spectra of the $\mathrm{Pt}(111)$ electrode in $0.1 \mathrm{M} \mathrm{Na}_{2} \mathrm{SO}_{4}+0.001 \mathrm{M} \mathrm{H}_{2} \mathrm{SO}_{4}$ solution
as: $\left(\frac{\Delta R}{R}\right)_{p}\left(\right.$ red), $\left(\frac{\Delta R}{R}\right)_{s} \times \frac{\left\langle E_{p, \text { ave }}\right\rangle^{2}}{\left\langle E_{s, \text { ave }}\right\rangle^{2}}$ (black), and $\left(\frac{\Delta R}{R}\right)_{p}-\left(\frac{\Delta R}{R}\right)_{s} \times \frac{\left\langle E_{p, \text { ave }}\right\rangle^{2}}{\left\langle E_{s, \text { ave }}\right\rangle^{2}}$ (blue).
The incident angle and cavity thickness is $28.5^{\circ}, 5.0 \mu \mathrm{~m}$.


Fig. 4 Ratio of reflectivities from the window|solution to the windowair interface for two configurations of the experimental system optimized for the angle of incidence $\sim 31^{\circ}$ and $\sim 28^{\circ}$ (p-polarized light).
layer thickness and angle of incidence. Fig. 4 plots the experimental $R(s) / R(a)$ curves for two configurations of the experimental set-up; optimized for $\sim 31^{\circ}$ (top curve) and optimized for $\sim 28^{\circ}$ bottom curve. Fig. 5 plots the simulated $R(s) / R(a)$ curves for several angles of incidence. The simulated curves reproduce the experimental. It can be seen that the reflectivity of $\mathrm{ZnSe} \mid \mathrm{H}_{2} \mathrm{O}$ interface is increasing with the increase in the angle of incidence.


Fig. 5 For $\mathrm{ZnSe} \mid \mathrm{H}_{2} \mathrm{O}$ system, simulated $\mathrm{R}(\mathrm{s}) / \mathrm{R}(\mathrm{a})$ curves for various angles of incidence, p-polarized light.

At this point, the data treatment procedure was altered. The angle of incidence was determined from the $R(s) / R(a)$ curve and then the thickness of the thin layer cavity was determined from the fit of $R(e) / R(a)$ in the range between $3000-1800 \mathrm{~cm}^{-1}$ wavenumbers where $R(e)>R(s)$. The angle of incidence was only allowed to vary only $\pm 1^{0}$ from the value determined from the $R(s) / R(a)$ curve. The fit shown in Fig. 6 A was performed using formula $R=\frac{f^{*} R(e)-R(s)}{R(a)-R(s)}$. The fit in Fig. 6B was performed using the formula $R=\frac{f^{*} R(e)-R(s)}{R(a)}$ where $f^{*} \sim 1.1$ is a factor taking into account that the electrode size was smaller than the footprint of the IR beam.


Fig. 6 Experimental and fitted IR reflectivity of the $\mathrm{Pt}(111)$ electrode in $0.1 \mathrm{M} \mathrm{Na}_{2} \mathrm{SO}_{4}+0.001 \mathrm{M}$ $\mathrm{H}_{2} \mathrm{SO}_{4}$ solution for p-polarized light. A: The fitted angle of incidence and cavity thickness are $31^{0}$ and $4.9 \mu \mathrm{~m}$. B: The fitted angle of incidence and the cavity thickness are $31^{\circ}$ and $2.8 \mu \mathrm{~m}$.

With these new values for the angle of incidence and cavity thickness, the s-polarized spectrum, after correcting for the ratio of the MSEFS, can be used to properly remove the IR contributions from solution species in the p-polarized spectrum, which is illustrated in Fig. 7.

Fig. 7A and 7B show the correction of the p-polarized spectra using the angles of incidence and the cavity thicknesses determined from the fitted curves in Fig. 6A and 6B, respectively. It appears that the experimental spectrum in Fig. 7A, fit using the data from Fig. 6A, gives a somewhat better correction compared to the p-polarized
spectrum in Fig. 7B, which was fit with the parameters obtained from Fig. 6B.


Fig. 7 Calculated IR spectra of the $\operatorname{Pt}(111)$ electrode in $0.1 \mathrm{M} \mathrm{Na}_{2} \mathrm{SO}_{4}+0.001 \mathrm{M} \mathrm{H}_{2} \mathrm{SO}_{4}$ solution in terms of $\left(\frac{\Delta R}{R}\right)_{p}($ red $),\left(\frac{\Delta R}{R}\right)_{s} \times \frac{\left\langle E_{p, \text { ave }}\right\rangle^{2}}{\left\langle E_{s, \text { ave }}\right\rangle^{2}}$ (black) and $\left(\frac{\Delta R}{R}\right)_{p}-\left(\frac{\Delta R}{R}\right)_{s} \times \frac{\left\langle E_{p, \text { ave }}\right\rangle^{2}}{\left\langle E_{s, \text { vev }}\right\rangle^{2}}$ (blue).

To check this procedure, the optical system was realigned to an angle of incidence $\sim 28^{\circ}$. Fig. 8 plots the corresponding single reflectivities at this new alignment. The reflectivity at the $\mathrm{H}_{2} \mathrm{O} \mid \mathrm{ZnSe}$ interface is now much smaller than the reflectivity at the $\mathrm{Au}\left|\mathrm{H}_{2} \mathrm{O}\right| \mathrm{ZnSe}$ spectrum in the wavenumber range of $1200-3000 \mathrm{~cm}^{-1}$.

This spectral range is used to calculate the thin cavity thickness and angle incidence from the ratio $R(e) / R(a)$ using standard procedure described in references 32 and 38. The Fig. 9A shows that the fit from this procedure is quite poor. The Fig. 9B shows a superior good fit to the experimental data using $\{R(e)-R(s)\} / R(a)$ where the


Fig. 8 Single beam reflectivities obtained from: $R(e)-\mathrm{Pt}\left|\mathrm{H}_{2} \mathrm{O}\right| \mathrm{ZnSe} ; R(a)-\operatorname{air} \mid \mathrm{ZnSe}$ and $R(s)-\mathrm{H}_{2} \mathrm{O} \mid \mathrm{ZnSe}$ interface when the system was optimized to angle incidence $\sim 28^{\circ}$ in a $0.1 \mathrm{M} \mathrm{Na}_{2} \mathrm{SO}_{4}+0.001 \mathrm{M} \mathrm{H}_{2} \mathrm{SO}_{4}$ solution.
reflectivity $R(e)$ was corrected for the reflectivity at the window|solution interface. The angle and thickness parameters determined from the fit are $28^{\circ}$ and $4.1 \mu \mathrm{~m}$, respectively.


Fig. 9 Fits of the thin cavity thickness for the $\operatorname{Pt}(111)$ electrode in $0.1 \mathrm{M} \mathrm{Na}_{2} \mathrm{SO}_{4}+0.001 \mathrm{M} \mathrm{H}_{2} \mathrm{SO}_{4}$ solution with the setup aligned for $\sim 28^{\circ}$ angle of incidence. Left panel shows the fit for $R(e) / R(a)$ and right panel is the fit for $\{R(e)-R(s)\} / R(a)$. The angle of incidence and thin cavity thickness for the right panel is $28^{\circ}$ and $4.1 \mu \mathrm{~m}$, respectively.


Fig. 10 Calculated IR spectra of the $\mathrm{Pt}(111)$ electrode in $0.1 \mathrm{M} \mathrm{Na}_{2} \mathrm{SO}_{4}+0.001 \mathrm{M} \mathrm{H}_{2} \mathrm{SO}_{4}$ solution as: $\left(\frac{\Delta R}{R}\right)_{p}$ (red), $\left(\frac{\Delta R}{R}\right)_{s} \times \frac{\left\langle E_{p, \text { ave }}\right\rangle^{2}}{\left\langle E_{s, \text { ave }}\right\rangle^{2}}$ (black), and (c): $\left(\frac{\Delta R}{R}\right)_{p}-\left(\frac{\Delta R}{R}\right)_{s} \times \frac{\left\langle E_{p, \text { ave }}\right\rangle^{2}}{\left\langle E_{s, \text { ave }}\right\rangle^{2}}$ (blue) for the experiment where the incident angle and cavity thickness is $28^{\circ}$ and $4.1 \mu \mathrm{~m}$, respectively.

Using these values for the angle of incidence and cavity thickness, the spectra acquired using s-polarized light multiplied by the ratio of MSEFS shows a good fit with features observed by the species in solution for p -polarized spectrum, which is
illustrated in Fig. 10 (Note: the $\mathrm{S} / \mathrm{N}$ for the spectra in Fig. 10 is much poorer than the spectra shown in Fig. 7 since the surface enhancement at $\sim 28^{\circ}$ is less than that at $\sim 31^{\circ}$ ).

Finally, $\Delta R_{\text {ads }}$ can be calculated for two experiments at $28^{\circ}$ and $31^{\circ}$ angle of incidence using the following expression:

$$
\Delta R_{\text {ads }}=\frac{\left(\frac{\Delta R}{R}\right)_{p}-\left(\frac{\Delta R}{R}\right)_{s} \times \frac{\left\langle E_{p, \text { average }}\right\rangle^{2}}{\left\langle E_{s, \text { average }}\right\rangle^{2}}}{\left\langle E_{p, z=0}\right\rangle^{2}}
$$

The resulting calculated spectra are shown in Fig. 11 where $\Delta R_{\text {ads }}$ should be independent of gap thickness and incident angle. It can be seen the shape and intensity of $\Delta R_{\text {ads }}$ is very similar in two experiments, confirming the accuracy of our procedure.


Fig. $11 \Delta R_{\text {ads }}$ spectra calculated for the two experiments; red line $31^{\circ}$ and black line $28^{\circ}$ angle of incidence. The reflectivity of electrode surface is calculated by different formulas.

## Conclusions

1. When working with a ZnSe prism at an incident angle near of the global maximum of the MSEFS, one cannot use the standard method of fitting the experimental $R(e) / R(a)$ data to the ratio calculated from optical constants since the reflectivity at the $\mathrm{H}_{2} \mathrm{O} \mid \mathrm{ZnSe}$ is too high. In the regions that correspond to strong water absorption (above $3000 \mathrm{~cm}^{-1}$ and $\sim 1650 \mathrm{~cm}^{-1}$ ), the IR radiation is primarily reflected from the window|water interface and the shape of the water bands is distorted in experimental $R(e) / R(a)$ spectrum.
2. The calculated fit to $\{R(e)-R(s)\} /\{R(a)-R(s)\}$ always results in a better fit than
$R(e) / R(a)$ since the reflectivities $R(e)$ and $R(a)$ are corrected for the IR reflectivity at the window|solution interface.
3. In future experiments, the single reflectivities of $R(e), R(s)$ and $R(a)$ should be compared prior to performing any SNIFTIRS experiment in order to decide on the most appropriate method for determining the correct angle of incidence and thin layer cavity thickness.

## 2. CV curves of the $\mathrm{Pt}(111)$ electrode $0.001 \mathrm{M} \mathrm{H}_{2} \mathrm{SO}_{4}+0.1 \mathrm{M} \mathrm{Na}_{2} \mathrm{SO}_{4}$ solution before and after IR experiment



Fig. 12 CV curves of the $\mathrm{Pt}(111)$ electrode $0.001 \mathrm{M} \mathrm{H}_{2} \mathrm{SO}_{4}+0.1 \mathrm{M} \mathrm{Na}_{2} \mathrm{SO}_{4}$ solution before and after IR experiment. The scan rate is $50 \mathrm{mV} \cdot \mathrm{s}^{-1}$

## 3. SNIFTIR Spectra of the $\operatorname{Pt}(111)$ Electrode in $0.1 \mathbf{M ~ N a}_{2} \mathrm{SO}_{4}+\mathbf{0 . 0 0 1}$

## $\mathrm{M} \mathrm{H}_{2} \mathrm{SO}_{4}$ Solution at Different $\boldsymbol{E}_{S}$



Fig. 13 SNIFTIRS spectra of the $\operatorname{Pt}(111)$ electrode in $0.1 \mathrm{M} \mathrm{Na}_{2} \mathrm{SO}_{4}+0.001 \mathrm{M} \mathrm{H}_{2} \mathrm{SO}_{4}$ solution at (A) p-polarized light, and (B) s-polarized light. $E_{S}$ is indicated in the figure, and $E_{R}$ is 0.04 V .

## 4. $\Delta R_{\text {ads }}$ Spectra of the $\operatorname{Pt}(111)$ Electrode in $0.1 \mathrm{M} \mathrm{Na}_{2} \mathrm{SO}_{4}+0.001 \mathrm{M}$

## $\mathrm{H}_{2} \mathrm{SO}_{4}$ Solution at Different $E_{S}$



Fig. $14 \Delta R_{\text {ads }}$ spectra of the $\mathrm{Pt}(111)$ electrode in $0.1 \mathrm{M} \mathrm{Na}_{2} \mathrm{SO}_{4}+0.001 \mathrm{M} \mathrm{H}_{2} \mathrm{SO}_{4}$ solution. $E_{S}$ is indicated in the figure.

